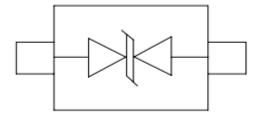
Description

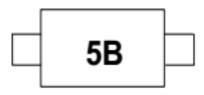
The JE05B1US50-2 is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The JE05B1US50-2 complies with the IEC 61000-4-2 (ESD) standard with ± 30 kV air and ± 30 kV contact discharge. It is assembled into an ultra-small lead-free SOD-523 package. The small size and high ESD surge protection make JE05B1US50-2 an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Circuit Diagram



Circuit and Pin Schematic

Marking Diagram



Transparent top view

5B:Device Marking Code



Features

- * 100W peak pulse power (8/20µs)
- * Low leakage: nA level
- * Operating voltage: 5V
- * Ultra low clamping voltage
- * One power line protects
- * Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV

Contact discharge: ±30kV

- IEC61000-4-5 (Lightning) 8A (8/20µs)
- * RoHS Compliant
- * Package: SOD-523

Applications

- * Cellular Handsets and Accessories
- * Personal Digital Assistants
- * Notebooks and Handhelds
- * Digital Cameras
- * Peripherals
- * Audio Players
- * Keypads, Side Keys, LCD Displays

Ordering Information

Part Number	Packaging	Reel Size	
JE05B1US50-2	3000/Tape & Reel	7 inch	



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

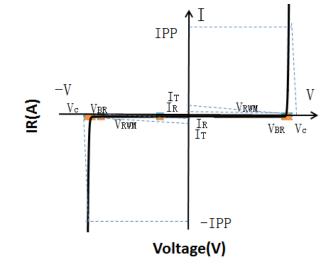
Parameter	Symbol	Value	Unit	
Peak Pulse Power (8/20µs)	Ppk	100	W	
Peak Pulse Current (8/20µs)	IPP	8	А	
ESD per IEC 61000-4-2 (Air)	VECD	±30	kV	
ESD per IEC 61000-4-2 (Contact)	VESD	±30		
Operating Temperature Range	TJ	-55to +125	°C	
Storage Temperature Range	Tstg	-55 to +150	°C	

Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Reverse Working Voltage	Vrwm				5	V
Breakdown Voltage	VBR	$I_T = 1 m A$	6		8	V
Reverse Leakage Current	I _R	$V_{RWM} = 5V$			0.2	μΑ
Clamping Voltage	Vc	IPP = $1A (8 \times 20 \mu s \text{ pulse})$			8	V
Clamping Voltage	Vc	$I_{PP} = 8A (8 \times 20 \mu s \text{ pulse})$			12.5	V
Junction Capacitance	Сл	VR = 0V, f = 1MHz			20	pF

Symbol	Parameter		
IT	Test Current		
Ірр	Maximum Reverse Peak Pulse Current		
Vc	Clamping Voltage @Ic		

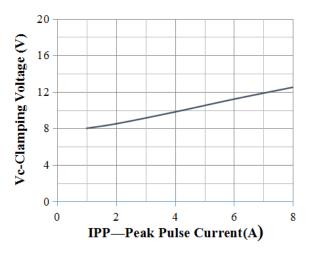
Portion Electronics Parameter



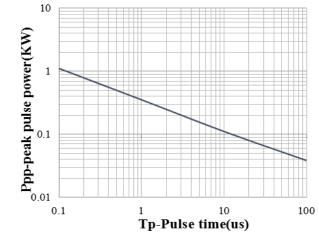
JE05B1US50-2



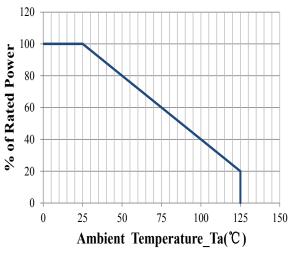
Typical Performance Characteristics (T_A=25°C unless otherwise Specified)



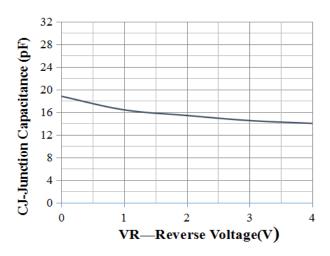
Junction Capacitance vs. Reverse Voltage



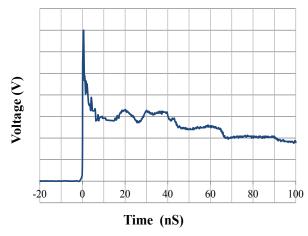
Peak Pulse Power vs. Pulse Time



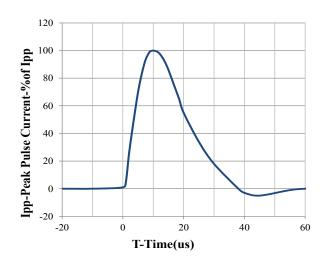
Power Derating Curve



Clamping Voltage vs. Peak Pulse Current



IEC61000-4-2 Pulse Waveform

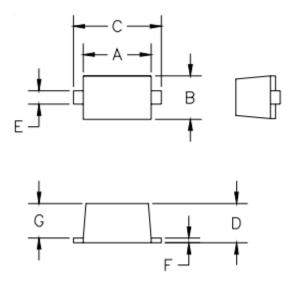


8 X 20us Pulse Waveform

JE05B1US50-2

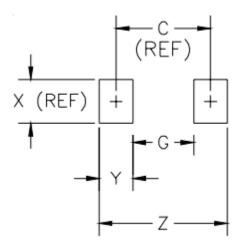


SOD-523 Package Outline Drawing (Dimensions in millimeters)



DIMENSIONS						
DIM™	INCHES		M	NOTE		
	MIN	MAX	MIN	MAX	NOTE	
A		.051	1.10	1.30	_	
В	.028	.035	0.70	0,90	_	
С	.059	.067	1.50	1.70	-	
D	.020	.028	0.50	0.70	_	
E	.010	.014	0.25	0,35	_	
F	.004	.008	0.10	0.20	_	
G	.020	.028	0.50	0.70	_	

Suggested Land Pattern



DIMENSIONS						
DIM™	INCHES		MM 1		NOTE	
	MIN	MAX	Min	MAX	NOTE	
С		.067	-	1,70	REF	
G	—	.043	_	1,10	_	
Х	-	.031	_	0.80	REF	
Y	-	.024	_	0.60	_	
Z	_	.091	_	2.30	_	

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